

DiaTherm™ CVD Diamond Heat Spreaders

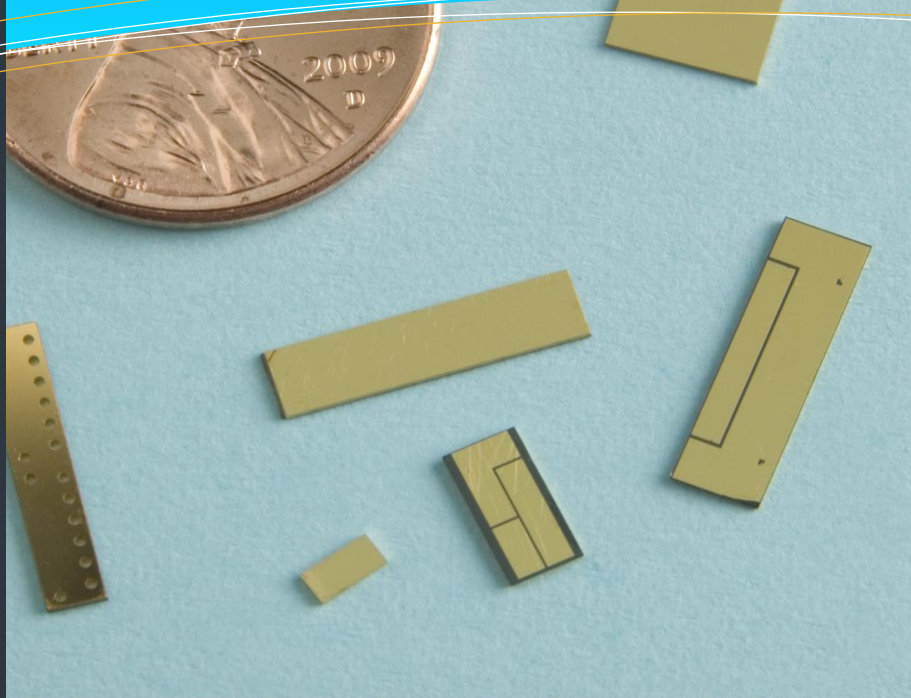
WHY DiaTherm™?

The buildup of heat can severely limit or impair the performance of electronic devices. Designed for thermal management applications, sp³'s DiaTherm™ diamond heat spreaders exhibit exceptionally high thermal diffusivity and greater thermal conductivity than other material choices:

- 3X greater than copper
- 5X greater than aluminum nitride or beryllium oxide
- 5X greater than refractory metals like copper tungsten or molybdenum copper

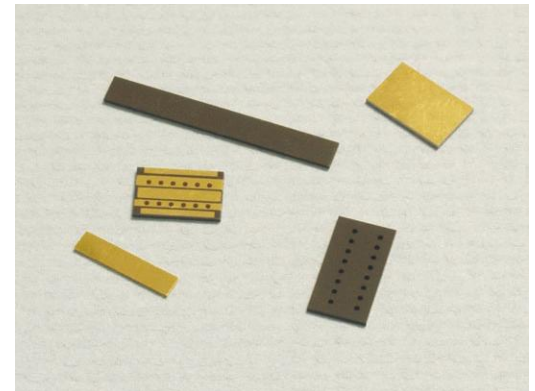
TYPICAL APPLICATIONS

- Laser diodes
- Laser diode arrays
- LED's
- RF power devices
- Other high power electronics



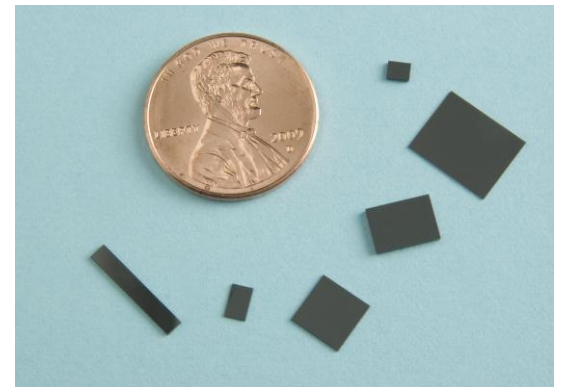
FEATURES

- Excellent thermal conductivity
- Highly polished/flat surface
- Electrically non-conductive
- Low coefficient of thermal expansion
- Diamond is completely inert
- DiaTherm™ can be easily laser machined and metallized
- Through vias easily machined



BENEFITS

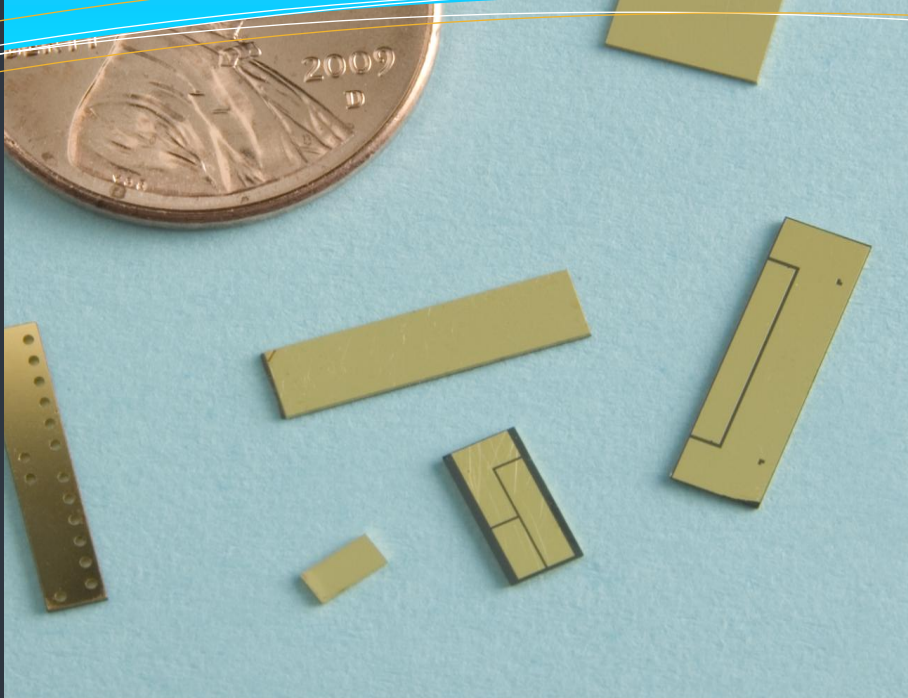
- Higher device performance and/or reliability
- Uniform void-free contact
- Electrical isolation – front to back
- Low CTE = excellent match for silicon devices
- No long term chemical reaction or degradation
- Large variety of shapes and sizes possible



For more information, call 877-773-9940
www.sp3diamondtech.com



DiaTherm™ CVD Diamond Heat Spreaders



METALLIZATION

CAPABILITIES

- Standard 1750A Ti/1250A Pt/5000A Au
- Adhesion layers – Ti, NiCr
- Barrier layers – Ni, Pt
- Conduction/bonding layers – Cu, Au, In, AuSn
- Multiple vias/patterns permissible

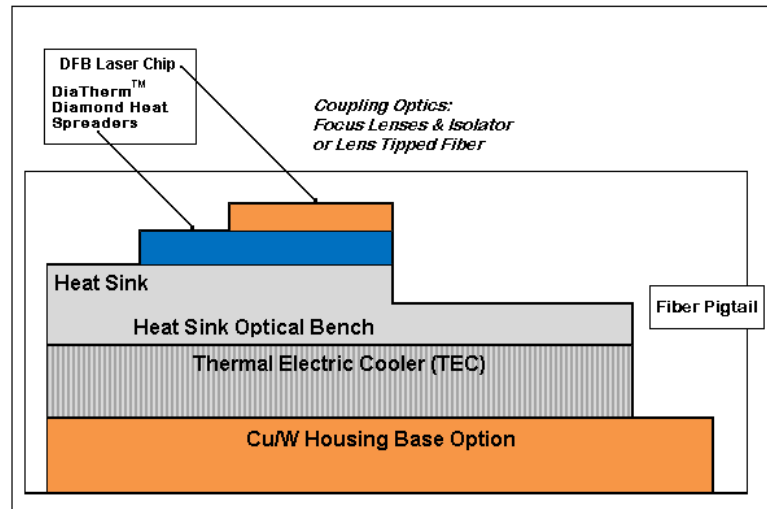
MATERIAL CHARACTERISTICS

- Thermal conductivity up to 1400 W/m²K (1000-1200 W/m²K typical)
- 100% polycrystalline diamond
- Density 3.5g.cm³
- Electric resistivity 10¹³ - 10¹⁶ ohms/cm (10¹⁵ ohms/cm typical)
- Coefficient of thermal expansion – 1.5 ppm /°C

PHYSICAL CHARACTERISTICS

- Coupon size up to 25mm x 25mm
- Thickness – 300 to 500 microns (Special sizes and thicknesses avail.)
- Size – typically 1.4 to 2X device size
- Dimensional accuracy – +/- 0.05 mm typical
- Through hole/via size – 1X material thickness minimum
- Surface finish device (A) side – <80 nm Ra
- Surface finish heat sink (B) side – <5 microns Ra
- Corner radii tolerance – < 3 microns

DiaTherm™ is typically positioned between the electronic device and a larger heat sink. The heat generated within the electronic device is most often concentrated in a small area and temperatures in this region rise much higher. By spreading the localized heat generated by the device, DiaTherm™ can improve cooling capability of laser die in assembled devices by 30% to 100%.



Diamond Heat Spreaders in Laser Packaging

About sp³ Diamond Technologies...

Founded in 1993 and headquartered in Santa Clara, California, USA, sp³ Diamond Technologies, Inc. is a privately held company that provides diamond products for advanced thermal management, cutting tool applications, diamond coating and material services, hot filament CVD diamond deposition reactors and deposition consulting services. sp³ Diamond Technologies is a subsidiary of sp³ Inc., a full service provider of products and services relating to thin-film and freestanding diamond deposition and other diamond materials.

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